Quenchings in crystals

Why are they important? Some Models Light Quenching (few comments) Ionization Quenching Measurements

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Journées Matière Sombre France

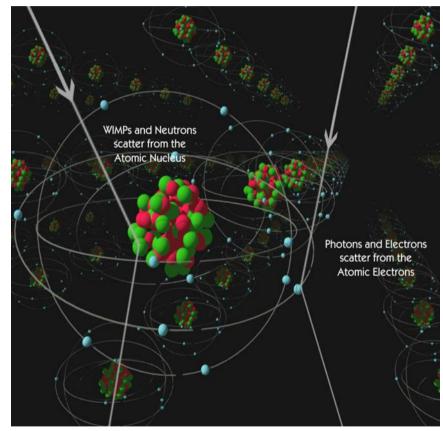
Quenching

Background

- E in keV-equivalent-electron (keV_{ee})
 - Calibration with γ rays (produce an electron recoil)
 - Monoenergetic sources easily available

WIMP signal

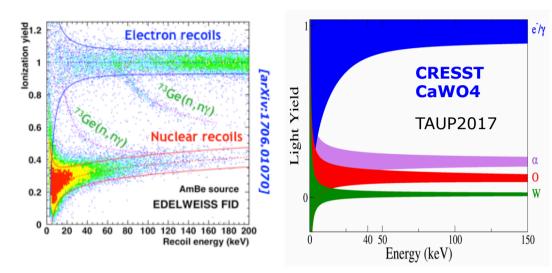
- E in keV-equivalent-nuclear-recoil (keV_{NR})
 - Calibration with neutron scattering (produce a nuclear recoil)
 - Monoenergetic neutron source not as easily available
 - Monoenergetic neutrons produce a continuous recoil energy spectrum
- $Q = factor to convert keV_{ee} to keV_{NR}$



cdms.berkeley.edu

Why do we need quenching?

- Needed for energy scale (non-phonon detectors) DAMIC, CoGeNT, DAMA... ... COHERENT
- Two-signal detectors: e⁻/NR/phonon-only discrimination



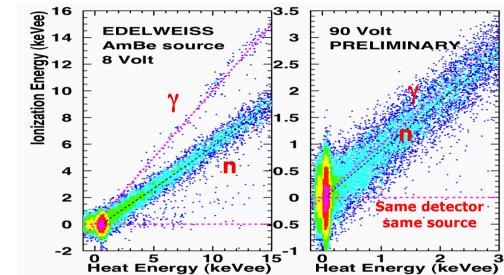
Signal	Quenching Needed for Energy scale	Provides good e ⁻ /NR discrimination	Good discrim. against phonon- only events
Phonon	No*		
Charge	YES	YES	YES (Q~0.3)
Scintillation	YES	YES	Not always (Q~0)

Why do we need quenching?

Luke-Neganov

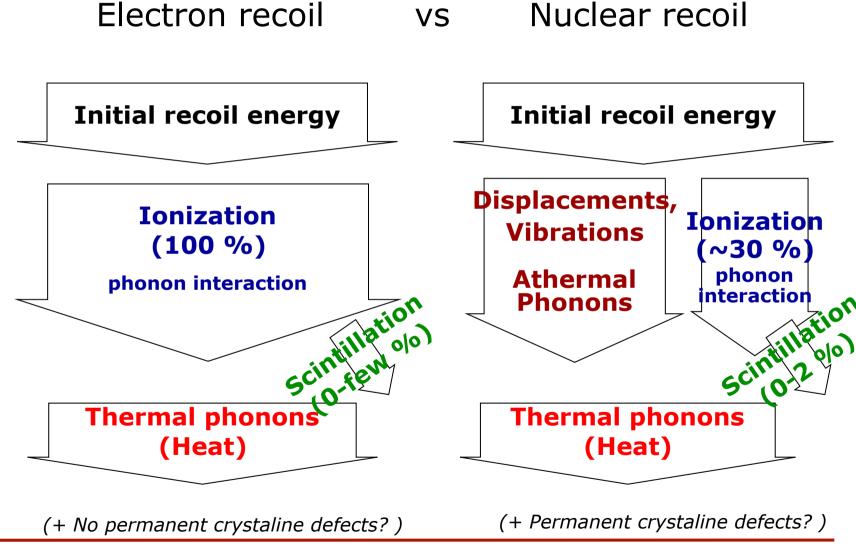
 amplification of phonon
 signal transforms
 "phonon signal" into
 "charge signal"

CDMS Lite EDELWEISS-LT



Signal	Quenching Needed for Energy scale	Provides good e ⁻ /NR discrimination	Good discrim. against phonon- only events
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Signals from recoils



Electron recoil energy scale (denominator)

Ionization yield (charge/eV)

- $< E_{e+e-pair} > = E_{GAP} + < E_{kinetic} > + < E_{phonon} >$
- eV/pair : 3.0 in Ge, 3.6 in Si
- Very small temperature dependence between 0 and 77K (kT=0.006 eV)

Light yield (photoelectron/eV)

- Depends on scintillation center concentration in crystal
- Depends on density of energy deposition
- Non-linearities at low energy (NaI, CsI)
- Large temperature dependence time constants) in general
- ~20 eV typical value

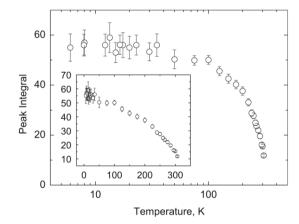
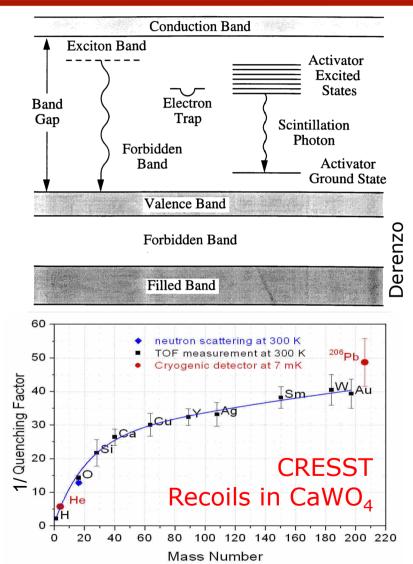


Fig. 1. Temperature dependence of the scintillation light response of BGO under α -excitation (²⁴¹Am). The inset shows the dependence on a linear temperature scale.

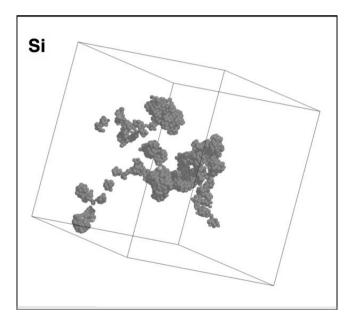
Inorganic scintillators (Nal, Csl, CaWO₄, ...)

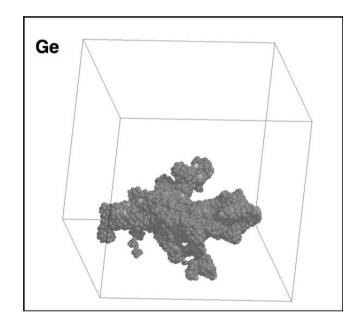
- A good scintillator should NOT reabsorb its own light
 Emission hv>E_{gap} from e⁻ conduction band is easily absorbed by valence e⁻
- Emission from less abundant ingap states is much less absorbed
- ~Birk's rule: if dE/dx is large, the population of the in-gap states is saturated: reduced emission per incident keV.
- Electron recoils are subject to this (E-dependent) quenching.
 Additional Lindhard quenching for nuclear recoils.
- Scintillation time constants may be affected: pulse shape discr.

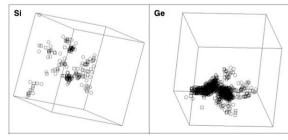


MD simulations of nuclear recoils

 Molecular Dynamic Simulations of « hot » atoms produced by a 10 keV Si or Ge recoil (Nordlund, 1998)





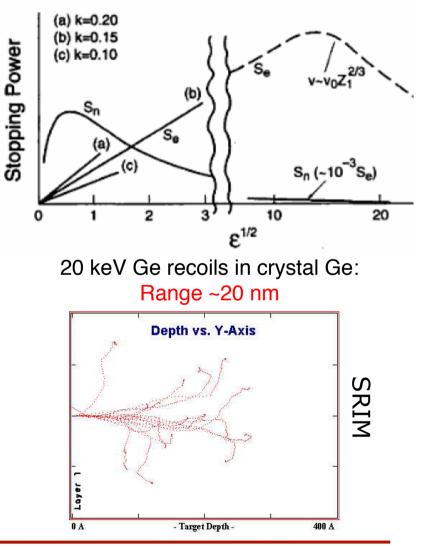


Permanent damages due to this « femtoGray » dose (negligible in metals, but maybe not in semiconductors?)

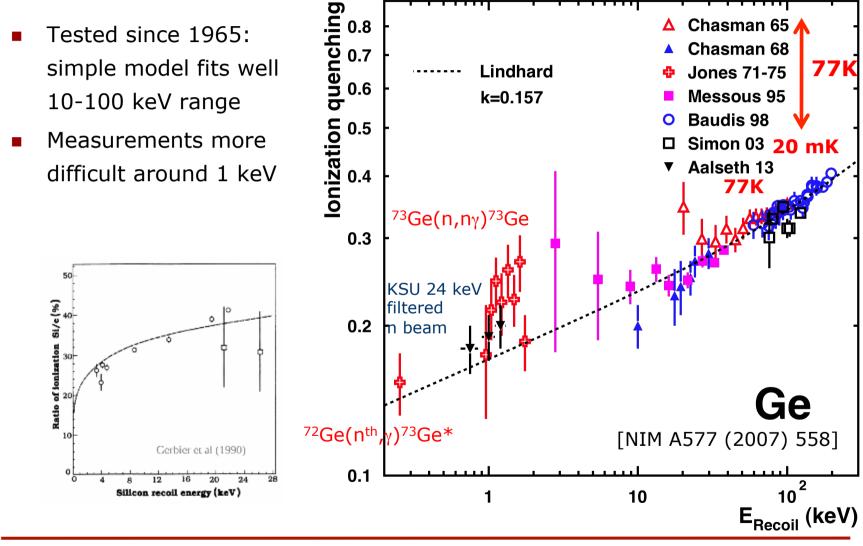
Ion recoils in crystal

- S_n and S_e: Nuclear and electronic stopping power dE/dx
 - S_n peaked at low energy (100 keV for Ge recoils in Ge)
 - $S_e = k \sqrt{\epsilon}$ at low energy, and small compared to S_n at 100 keV
- Lindhard, Scharff and Schiøtt

 (1963): use S_n and S_e to model of
 the energy loss during the cascade
 of ion-ion collisions to calculate the
 range, the ionization yield and its
 dispersion
- Model extensively used and tested, parameterized (k) using data



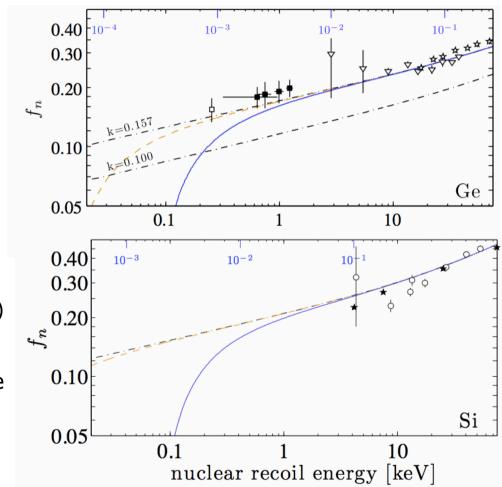
Lindhard vs Data



Lindhard critique: threshold effects

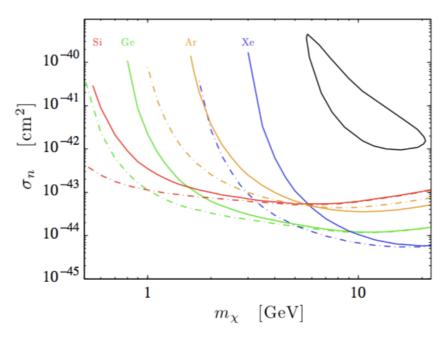
See e.g. Sorensen, PRD91 (2015) 083509 Also in: https://kicp-workshops.uchicago.edu/2015-lowecal/index.php

- Lindhard model assumes interaction between two neutral atoms (with screened Coulomb potential)... too simple?
- But: Threshold energy to excite a e⁺h⁻ pair (0.7 eV gap) ~100 eV for Ge?
- Also: average energy to ionize an e⁻ should play a role?
 S_e = k √ε - cte



This matters if you are...

•Searching for O(I) GeV dark matter via nuclear recoil scattering •Searching for CENNS from low-energy (e.g. reactor) neutrinos

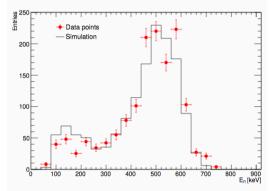




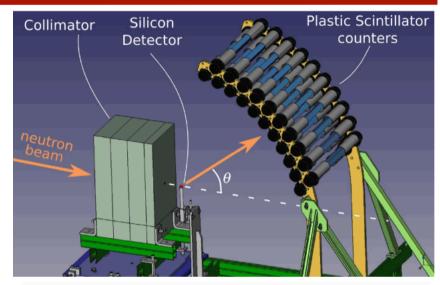
- Neutron beam/source
 - Monoenergetic or broad band? Try to avoid MC dependence...
- Detector size, surroundings
 - Multiple scattering inside the detector
 - Scattering of neutron before/after hitting the target
- Detector calibration near its threshold
 - Difficulty of low-energy γ -ray lines throughout the bulk of the detector
 - Efficiency measurement / trigger bias
- Tag of neutron scattering angle to reconstruct recoil energy

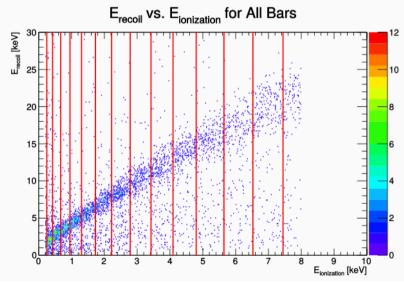
Measurements: Si with tagged n beam

- Antonella [arxiv:1702.00873]
- <700 keV Neutron beam</p>



- 29 mg Si drift diode target (minimal multiple scattering)
- Recoil energy deduced from scattering angle + Time of Flight in plastic scintillator counters

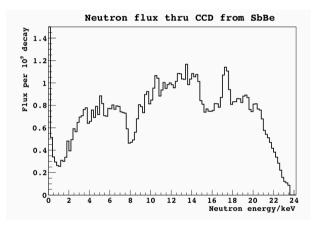




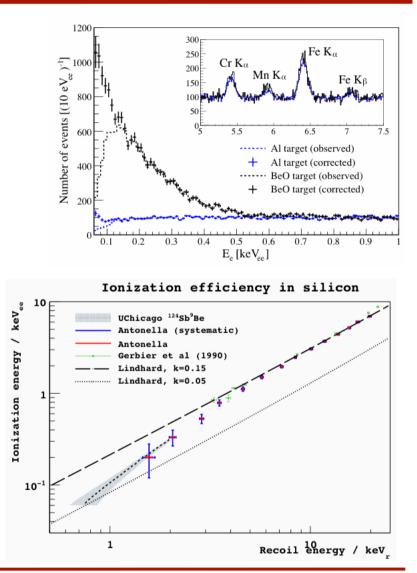
Si with ¹²⁴Sb-⁹Be source

arXiv:1608.00957

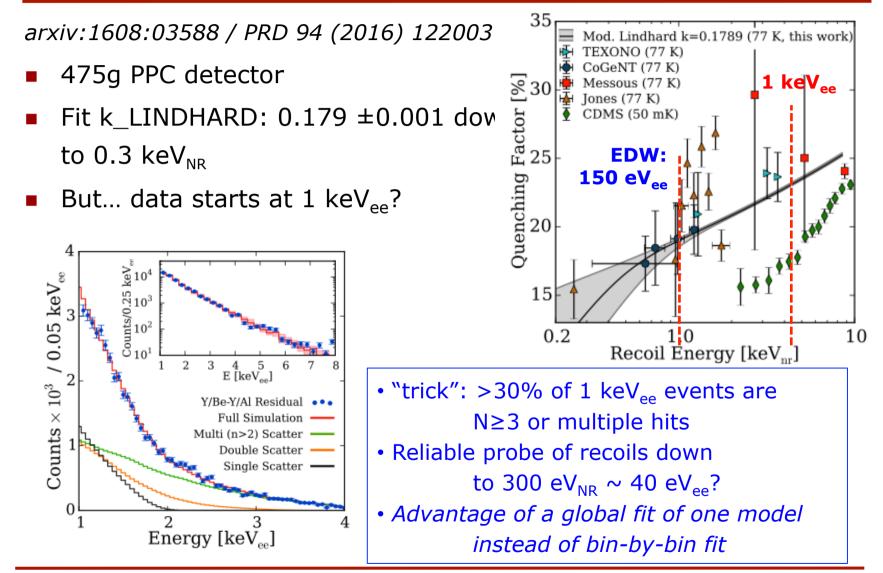
 ⁹Be(γ,n): continuous spectrum of <20 keV neutrons



- Use MC to fit Q model to data
- Both Si measurements show decrease wrt Lindhard close to 1 keVNR



Ge: recent Y/Be measurement

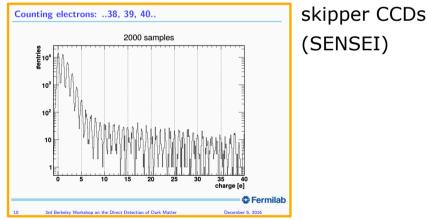


New idea: e-h pair counting

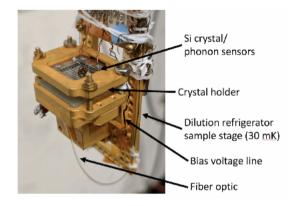
arXiv:1710.09335

- Electron-hole pair quantization in a high voltage (160V) cryogenic silicon detector (1 g) [CDMS phonon sensor]
- Here: pairs created by electron recoil (laser):
 3.8 eV/pair in Si





Idea: Spacing should change when observing nuclear recoil: spacing = 3.8 eV/Qion



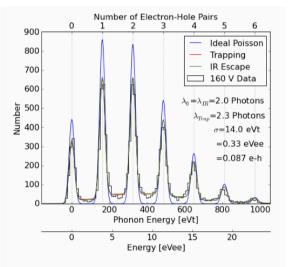


FIG. 5. (color online) Histogram of summed A+B data from Fig.[2] showing the excellent fit for a Poisson distribution. A small nonlinearity is taken out of the data prior to the fits (see text). The integer number of e^-h^+ pairs is shown above, the phonon crystal energy below (eVt), and an electron-equivalent energy scale (eVee) at bottom using the standard 3.8 eV per e^-h^+ pair^[13] Fits are performed including trapping and impact ionization (see text).

Ge: phonon quenching?

EDELWEISS, NIM A 577 (2007) 558

- If energy loss to permanent damage in nuclear collision, phonon quenching: $E_{phonon} = Q_{phonon} E_{recoil}$
- Q_{phonon} extracted by comparing apparent ionization Q_{ion} in cryogenics Ge detectors to direct Q_{ion} measurements
- Results: damage loss ~ $9\pm5\%$, consistent with measurement of Pb recoils in bolometers, and dominated by systematics on calibration and simulation of multiple scattering

120

100

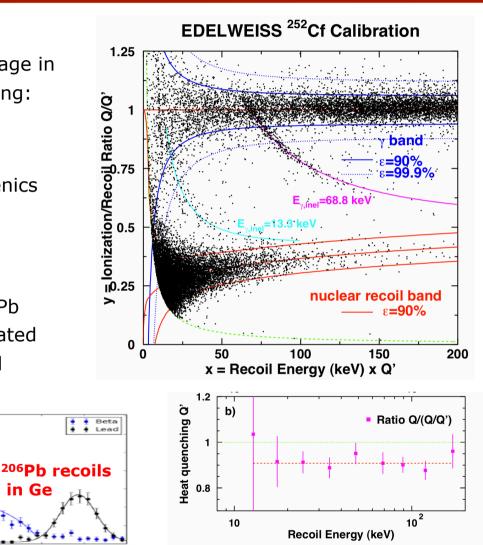
60

20

Events / keV

FID825 - Top side

Heat energy



November 30th, 2017

EDELWEISS

events

tagged surface

[JCAP05 (2016) 019]

Ge

- Ionization quenching measurements in Ge & Si at low energy very important to set the energy scale in the experiments DAMIC (Si) and EDELWEISS-LT (Ge)
- Threshold effects in Lindhard model hunted since 1968, first positive hints in recent Si measurements? To be confirmed in Ge [same physics?].
- A detailed understanding of detector physics and of systematic effects is required
 - Clear benefits of discussions within the community
- New ideas, strategies and collaborations are welcome

Quenching the Ge quenching controversies

- Caution: sometimes data shown in a way to exacerbate discrepancies
- ... as often, in fields where new models abound...

